

International **IR** Rectifier

242NQ030

SCHOTTKY RECTIFIER

240 Amp

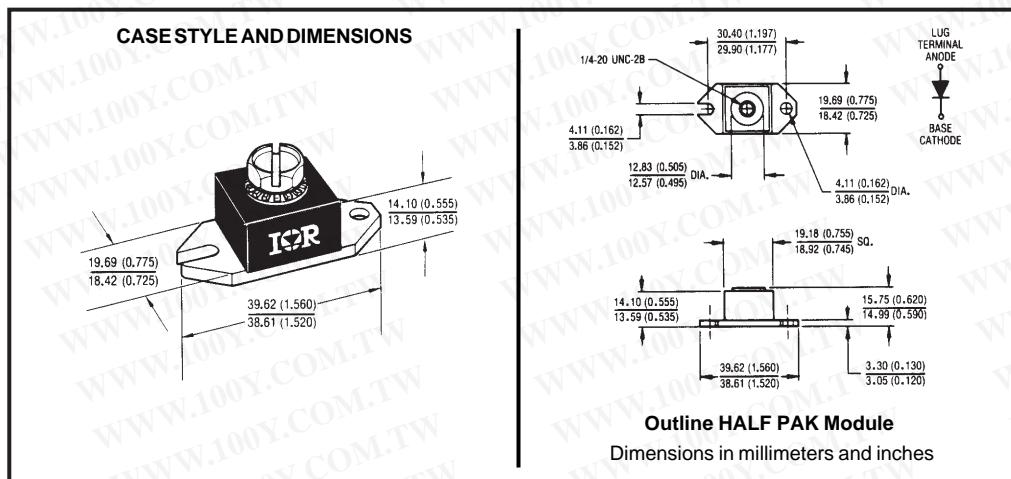
Major Ratings and Characteristics

Characteristics	242NQ030	Units
I _{F(AV)} Rectangular waveform	240	A
V _{RRM}	30	V
I _{FSM} @ tp=5 μs sine	27,000	A
V _F @ 240Apk, T _J =125°C	0.42	V
T _J range	-55 to 150	°C

Description/Features

The 242NQ030 high current Schottky rectifier module has been optimized for very low forward voltage drop, with moderate leakage. The proprietary barrier technology allows for reliable operation up to 150° C junction temperature. Typical applications are in switching power supplies, converters, free-wheeling diodes, and reverse battery protection.

- 150° C T_J operation
- Unique high power, Half-Pak module
- Replaces four parallel DO-5's
- Easier to mount and lower profile than DO-5's
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Very low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability



勝特力材料 886-3-5753170
 胜特力电子(上海) 86-21-54151736
 胜特力电子(深圳) 86-755-83298787
[Http://www.100y.com.tw](http://www.100y.com.tw)

242NQ030

PD-2.281 rev. A 12/97

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Voltage Ratings

Part number	242NQ030		
V_R Max. DC Reverse Voltage (V)	30		
V_{RWM} Max. Working PeakReverse Voltage (V)	30		

Absolute Maximum Ratings

Parameters	242NQ	Units	Conditions		
$I_{F(AV)}$ Max.AverageForwardCurrent * See Fig. 5	240	A	50%duty cycle @ $T_c = 111^\circ\text{C}$, rectangularwaveform		
I_{FSM} Max.PeakOneCycleNon-Repetitive Surge Current* See Fig. 7	27,000	A	5μs Sine or 3μs Rect.pulse	Following any rated load condition and with rated V_{RWM} applied	
	3000		10ms Sine or 6ms Rect. pulse		
E_{AS} Non-RepetitiveAvalancheEnergy	216	mJ	$T_j = 25^\circ\text{C}$, $I_{AS} = 48$ Amps, $L = 0.19$ mH		
I_{AR} RepetitiveAvalancheCurrent	48	A	Currentdecayinglinearlytozero in 1 μsec Frequency limited by T_j max. $V_A = 1.5 \times V_R$ typical		

Electrical Specifications

Parameters	242NQ	Units	Conditions		
V_{FM} Max. Forward Voltage Drop (1) * See Fig. 1	0.51	V	@ 240A	$T_j = 25^\circ\text{C}$	
	0.62	V	@ 480A		
	0.42	V	@ 240A	$T_j = 125^\circ\text{C}$	
	0.54	V	@ 480A		
I_{RM} Max. Reverse Leakage Current (1) * See Fig. 2	20	mA	$T_j = 25^\circ\text{C}$	$V_R = \text{rated } V_R$	
	1120	mA	$T_j = 125^\circ\text{C}$		
C_T Max. Junction Capacitance	14,800	pF	$V_R = 5V_{DC}$ (test signal range 100Khz to 1Mhz) 25°C		
L_s Typical Series Inductance	5.0	nH	From top of terminal hole to mounting plane		
dv/dt Max. Voltage Rate of Change (Rated V_R)	10,000	V/ μs			

(1) Pulse Width < 300μs, Duty Cycle < 2%

Thermal-Mechanical Specifications

Parameters	242NQ	Units	Conditions	
T_j Max.JunctionTemperatureRange	-55 to 150	°C		
T_{stg} Max.StorageTemperatureRange	-55 to 150	°C		
R_{thJC} Max.ThermalResistanceJunction to Case	0.20	°C/W	DCoperation * See Fig. 4	
R_{thCS} Typical Thermal Resistance, Case to Heatsink	0.15	°C/W	Mountingsurface,smoothandgreased	
wt ApproximateWeight	25.6(0.9)	g(oz.)		
T MountingTorque	Min.	40(35)	Kg-cm (lbf-in)	Non-lubricatedthreads
	Max.	58(50)		
TerminalTorque	Min.	58(50)		
	Max.	86(75)		
Case Style	HALF PAK Module			

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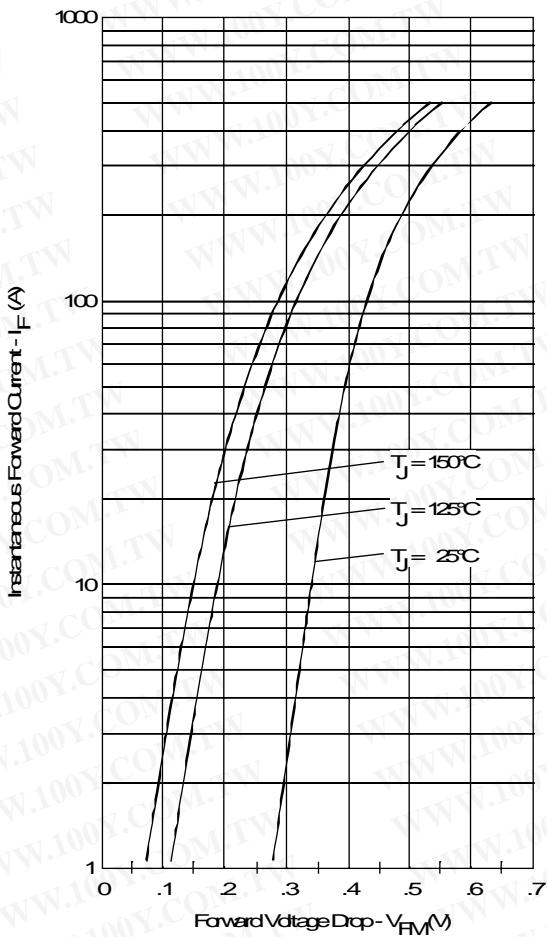


Fig. 1-Maximum Forward Voltage Drop Characteristics

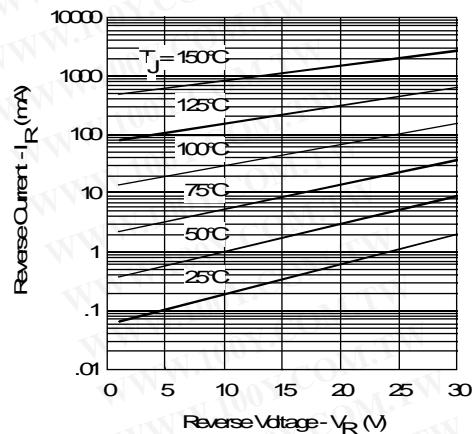


Fig. 2-Typical Values of Reverse Current Vs. Reverse Voltage

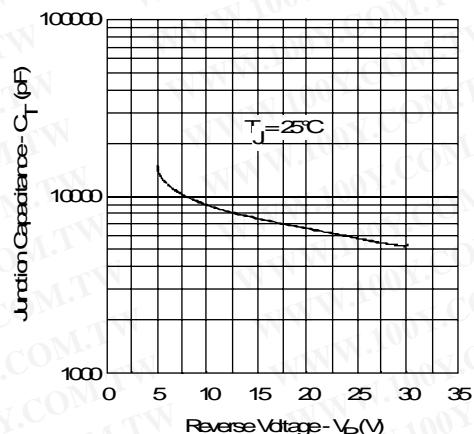


Fig. 3-Typical Junction Capacitance Vs. Reverse Voltage

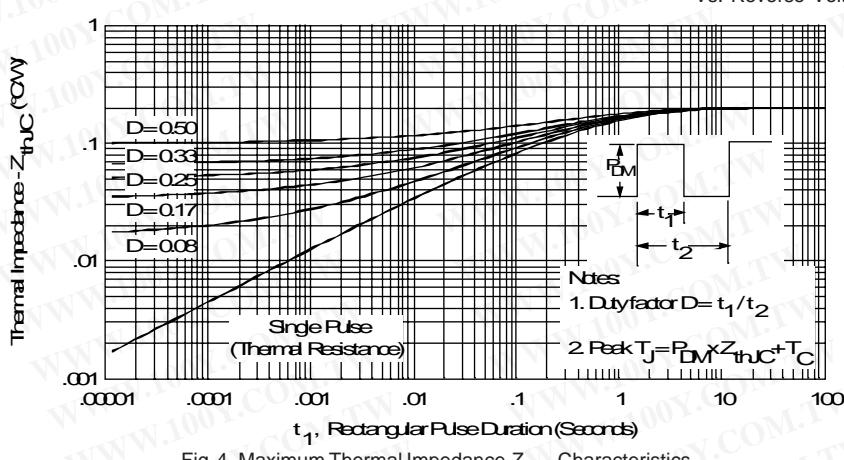


Fig. 4-Maximum Thermal Impedance Z_{thJC} Characteristics

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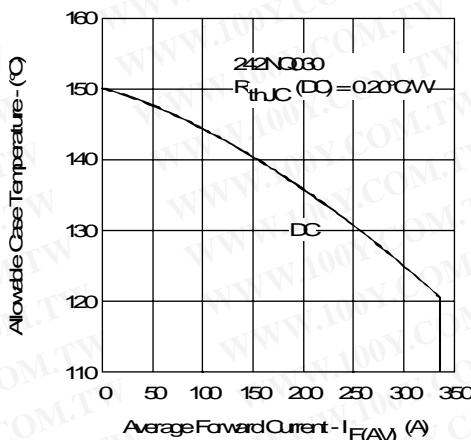


Fig.5-Maximum Allowable Case Temperature
 Vs. Average Forward Current

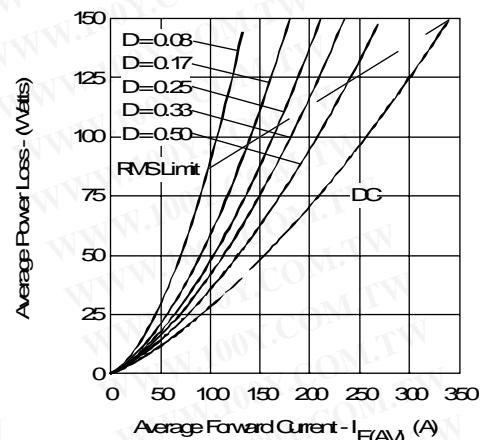


Fig.6-Forward Power Loss Characteristics

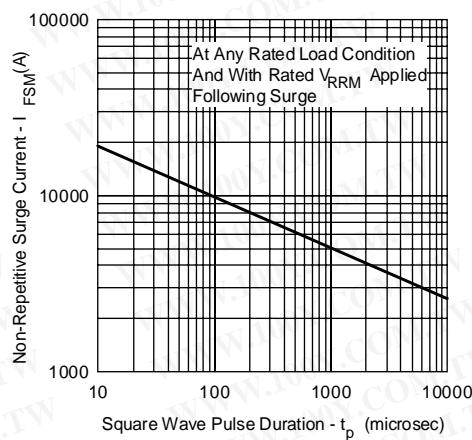


Fig.7-Maximum Non-Repetitive Surge Current

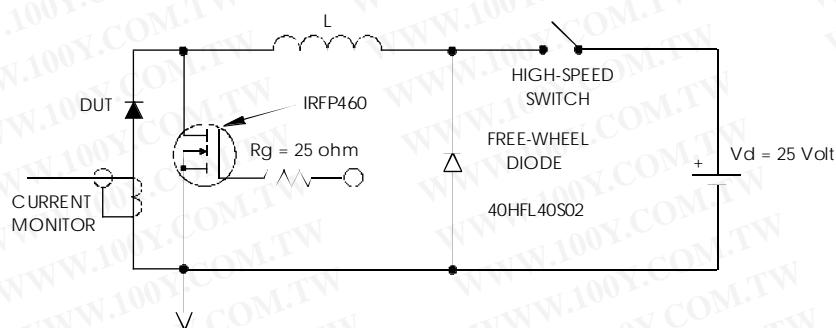


Fig.8-Unclamped Inductive Test Circuit